

Lecture Series

# Wireless Communications - Part IV - OWC - Visible Light Communication – Optical Rx

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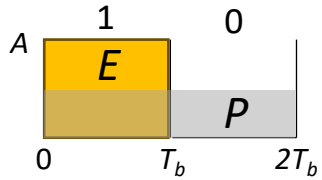
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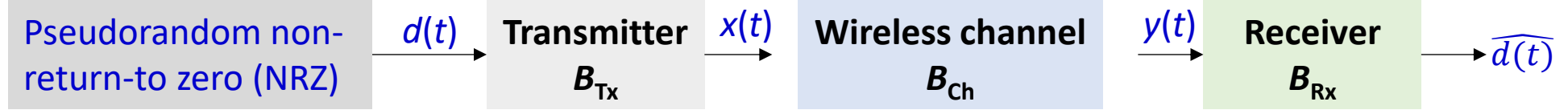
## Contents

- OWC – Receiver
- Types of front end Rxs
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  - Trans-impedance
- Equivalent circuit
- Noise sources
- Performance matrix
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  - Eye diagram
  - Trade-off

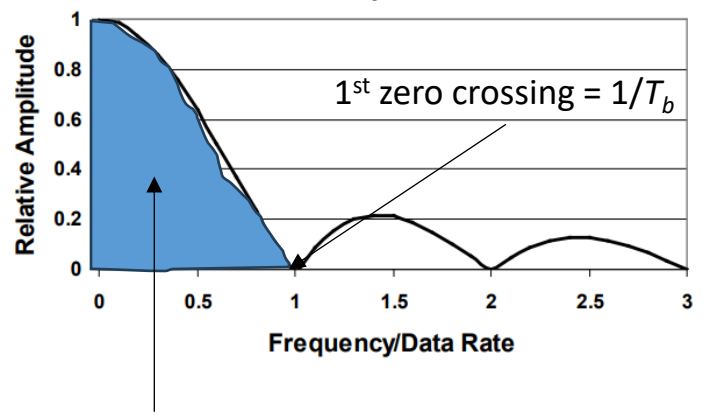
# OWC - System Block Diagram



Energy  $E = A^2 T_b$   
Average power  $P = A^2/2$



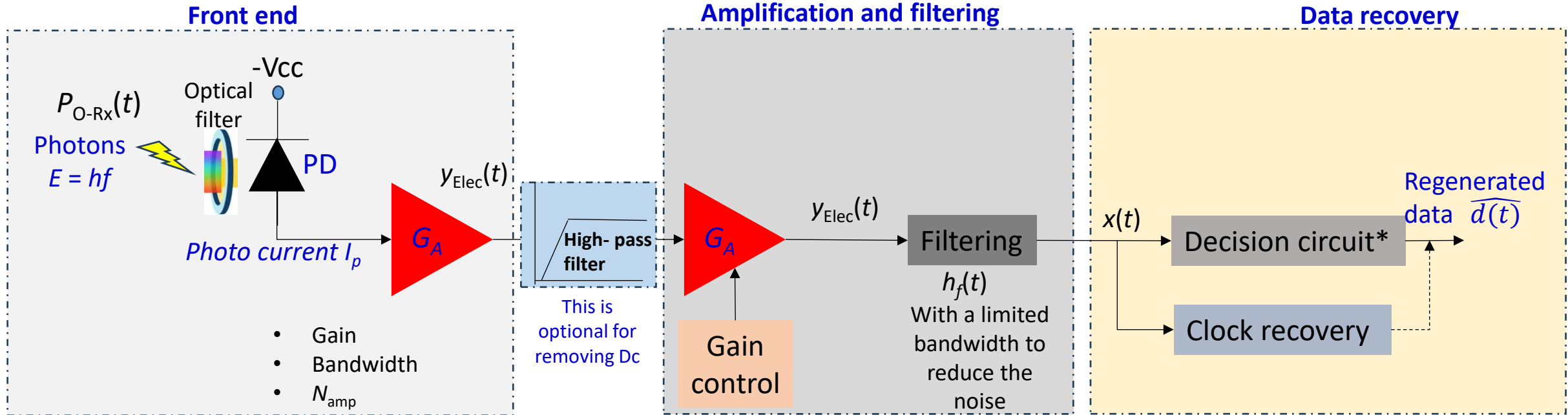
Frequency spectrum  
 $\text{Sinx}/x$



~ 93 of the power is accumulated at 75% of the data rate.

- For the data to be faithfully transmitted the channel needs to transmit the portion of the spectrum that contains most of the energy with minimal distortion, i.e.,  
 $B_{Ch} = 1/T_b = R_b$
- A non-flat frequency response  $\rightarrow$  ISI
- $B_{Rx} = 0.75 R_b$

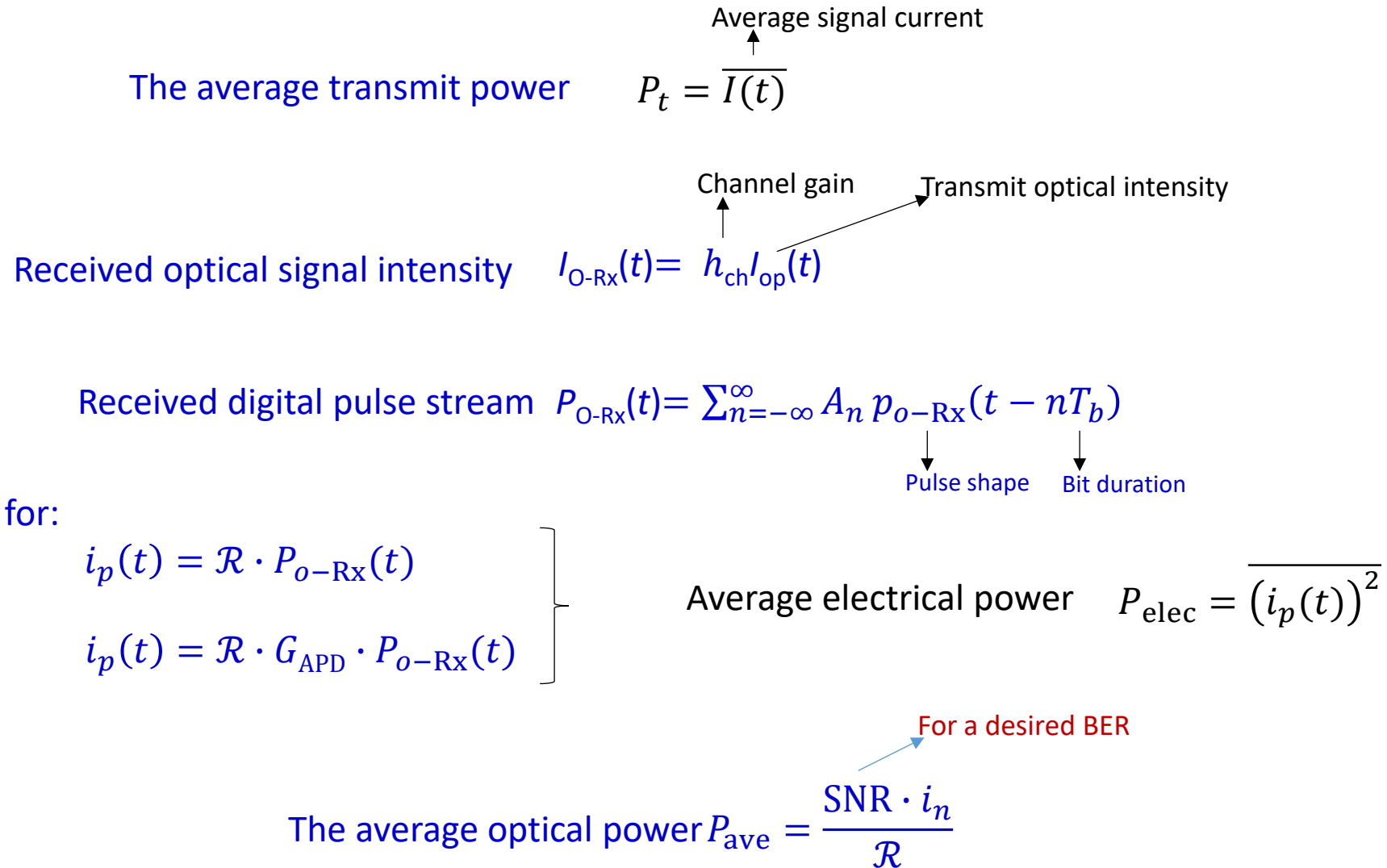
# OWC – Receiver – Block Diagram



\*This could be based on:

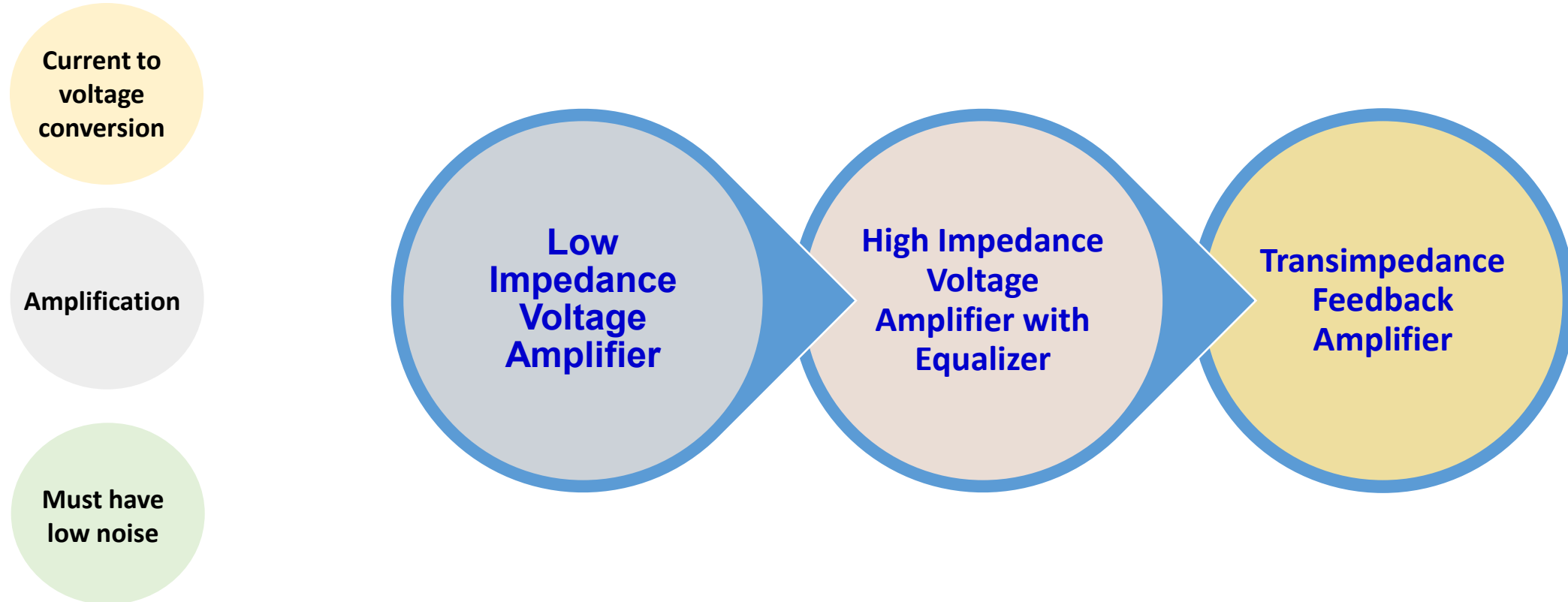
- A simple slicer
- A matched filter + slicer

# OWC – Receiver – Block Diagram



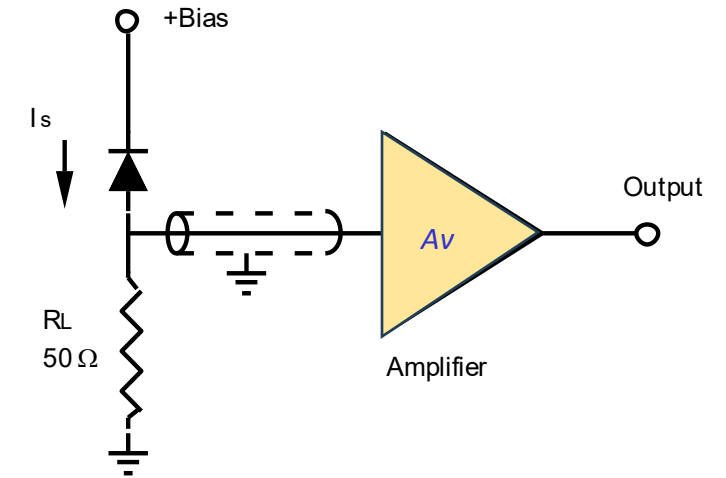
Photocurrent  $I_p =$  Average photocurrent (DC current)  $I_{p-DC} +$  Signal current  $i_{p-AC}(t)$

# OWC – Rx – Types of Front End

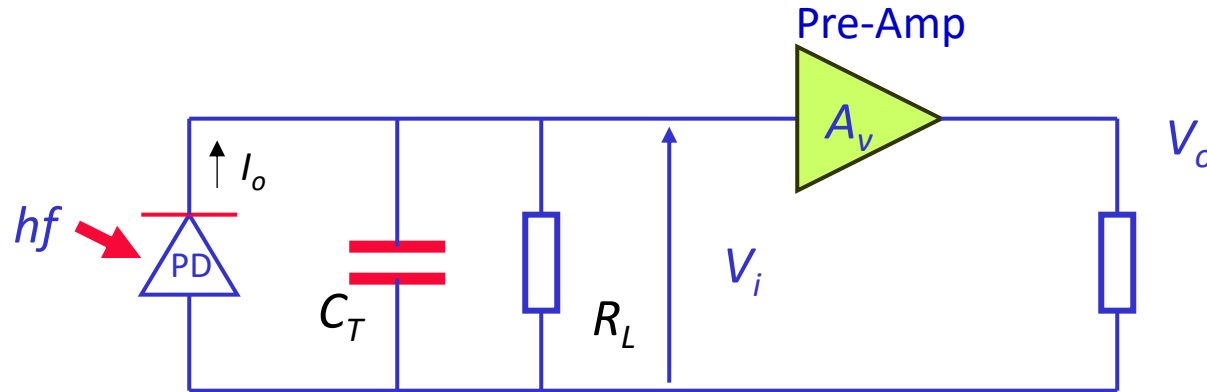


# OWC – Rx – Low Impedance Voltage Amplifier

- Simple
- Low sensitivity
- Limited dynamic range
- A large bandwidth
- It is prone to overload and saturation



# OWC – Rx – Low Impedance Voltage Amplifier



For equivalent circuit model for PD and amplifier see the lecture note on Optical PDs

$$R_T = R_{PD} || R_{PD} || R_{amp}$$

$$R_{amp} = \text{High}$$

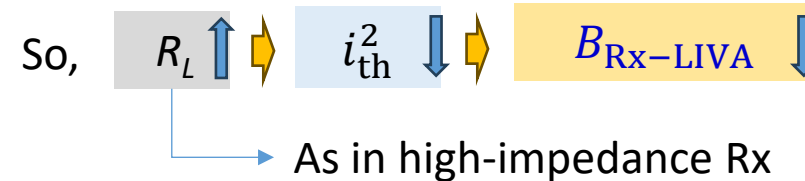
$$C_T = C_{PD} + C_{amp}$$

Has normally a low value, typically 50  $\Omega$

$$RC \text{ limited bandwidth } B_{Rx-LIVA} = \frac{1}{2\pi C_T R_T}$$

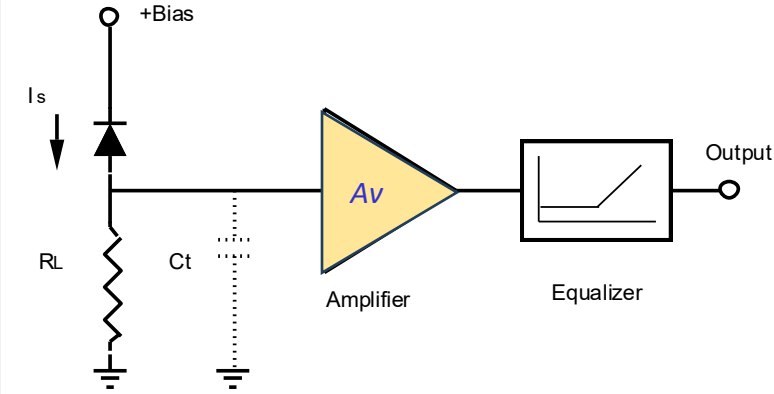
Assuming  $B_{amp} \gg B_{Rx-LIVA}$

Note, thermal noise  $i_{th}^2 = \frac{4kTB_{Rx}}{R_L}$



# OWC – Rx – High Impedance Voltage Amplifier (HIVA) with Equalizer

- Uses a resistor to develop a voltage proportional to the light detector current
- High sensitivity, due to lower  $i_{th}^2$
- If  $R_{in}$  of the high impedance circuit is too high:
  - the leakage current, caused by ambient light, could saturate the PIN diode, preventing the modulated signal from ever being detected
  - Saturation occurs when  $V_{RL}$ , due to the photodiode leakage current, approaches  $V_{bias}$
  - To prevent saturation, the PIN must maintain a bias voltage of at least a few volts
- Low dynamic range
- A smaller bandwidth → Using an equalizer
- Detector output is integrated over a long time constant, and is restored by differentiation

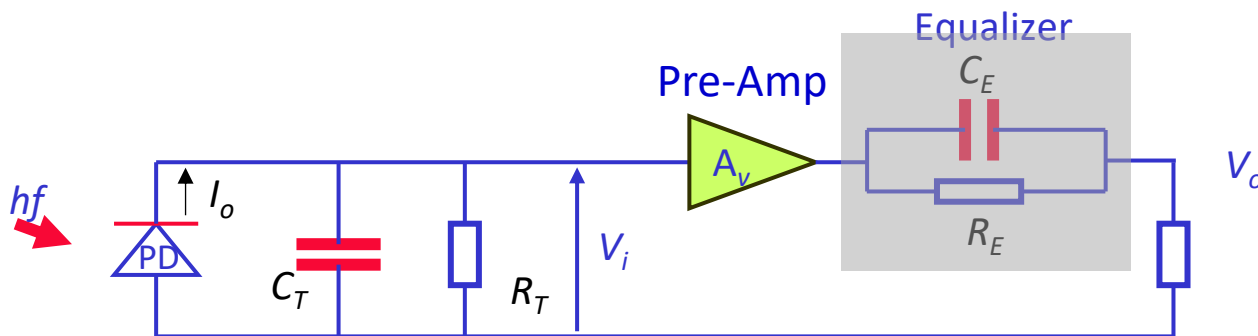


$$R_T = R_{PD} || R_{PD} || R_{amp} \quad R_{amp} = \text{High}$$

$$C_T = C_{PD} + C_{amp}$$

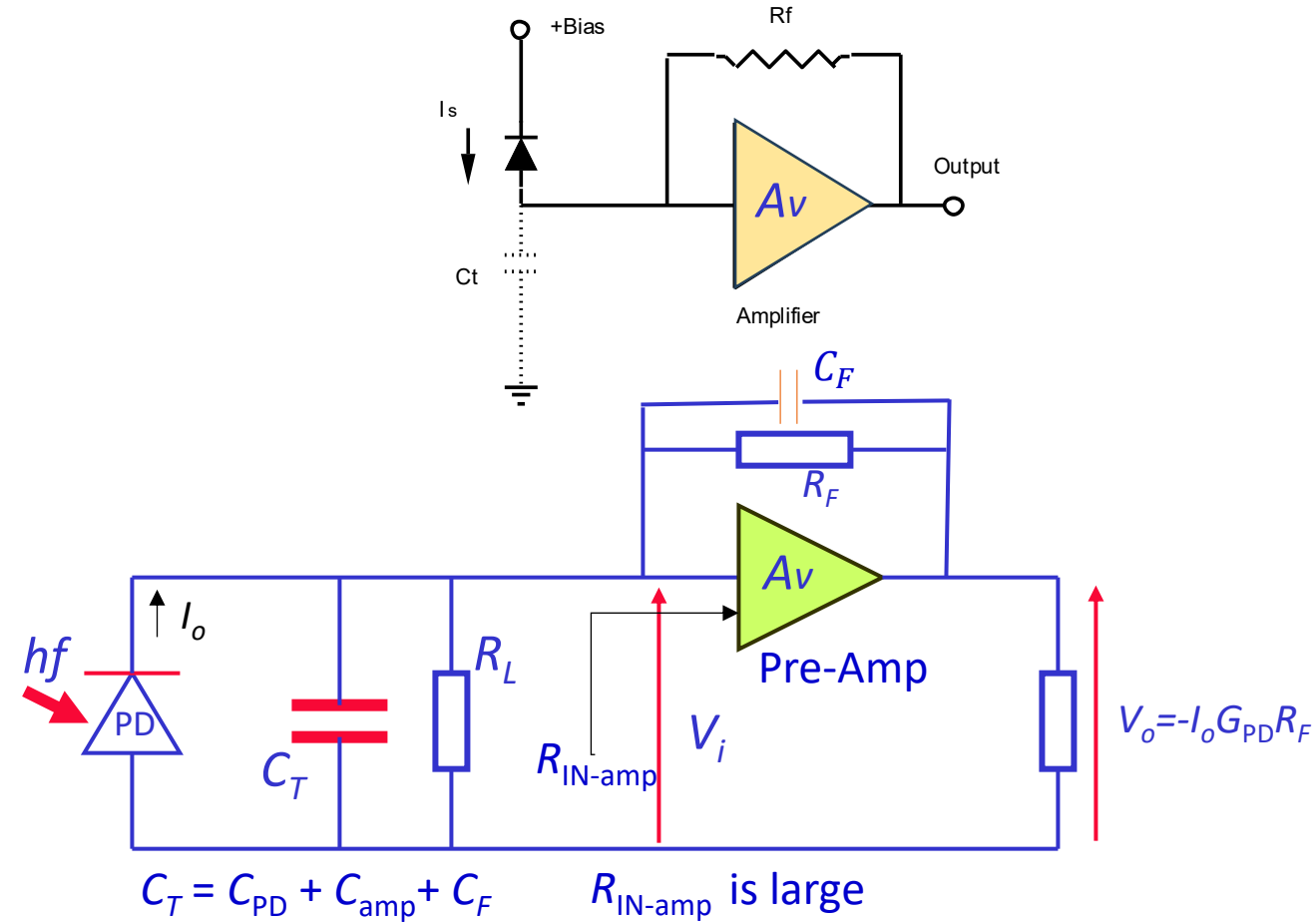
$$B_{Rx-HIVA} = \frac{1}{2\pi C_T R_T}$$

Assuming  $B_{amp} \gg B_{Rx-HIVA}$



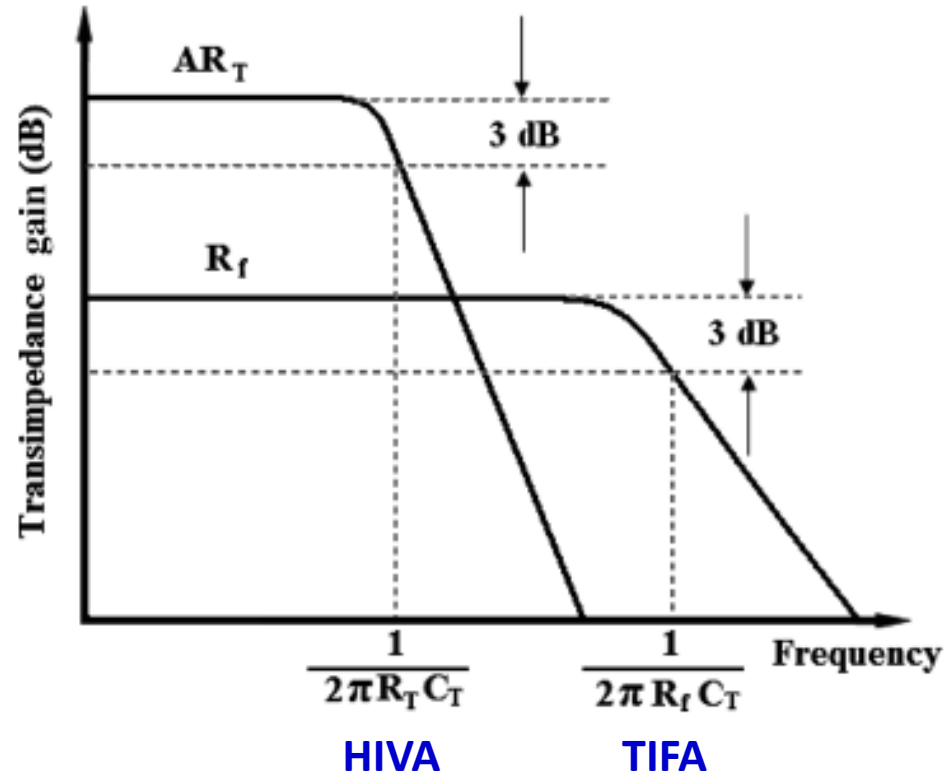
# OWC – Rx – Transimpedance Feedback Amplifier (TIFA)

- Best sensitivity → most widely used ✓
- Amplifier acts as a buffer –  $V_o \propto I_s$
- Low capacitance → Wide bandwidth
- Input bandwidth is extended by the factor  $A_v+1$
- Transimpedance is  $\sim R_F$
- $R_F$  can be made large → lower current noise
- With finite bandwidth amplifier, the TI transfer function is a 2<sup>nd</sup> order low-pass function → peaking in frequency domain and overshoot/ringing in time domain
- Susceptible to saturation
- No equalization
- Greater dynamic range (same gain at all frequencies)
- Reduced dynamic range
- Slightly higher noise figure than HIVA.



$$\text{Bandwidth } B_{TIFA} = \frac{A_v}{2\pi C_T R_F} \approx \frac{A_v}{2\pi C_F R_F}$$

# OWC – Rx – Frequency Response

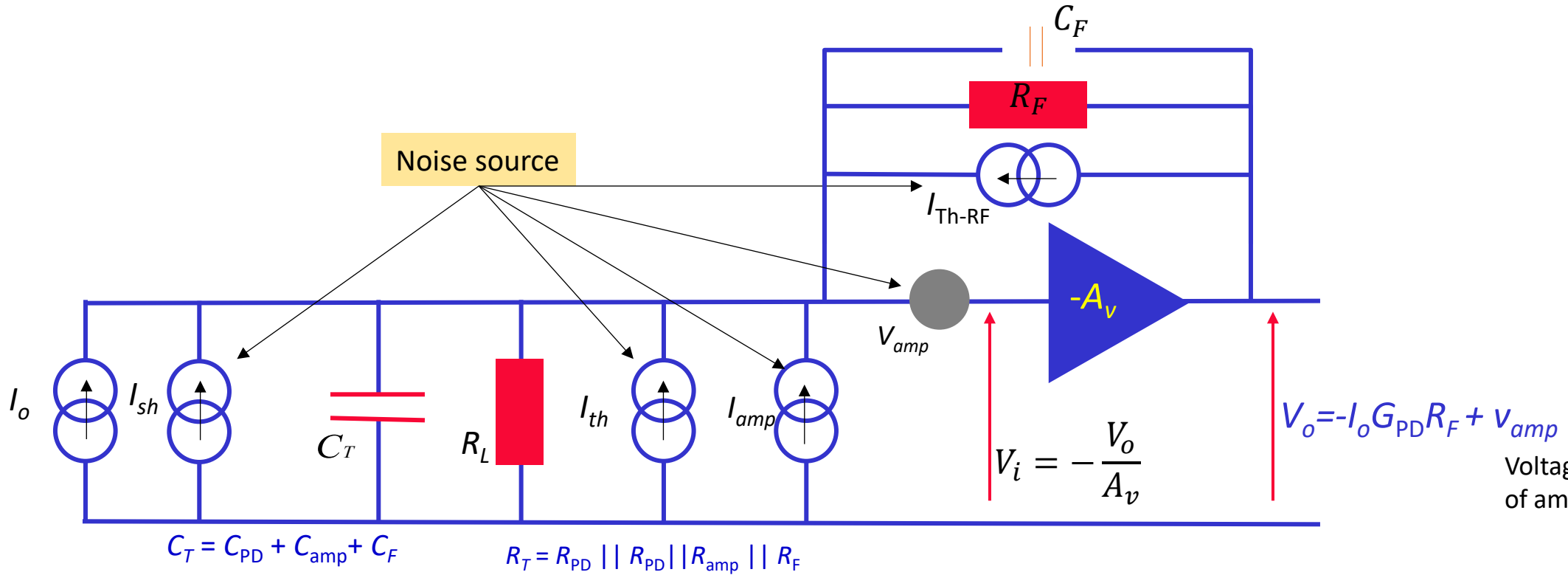


- TIFA has a lower gain and wide bandwidth.
- TIVA has a higher gain and lower bandwidth.

The gain ratio of HIVA to TIFA  $R_G = A_v \frac{R_T}{R_f} \gg 1$

The bandwidth ratio of HIVA to TIFA  $R_B = \frac{(1 + A_v) R_T}{R_f} \gg 1$

# OWC – Rx – TIFA – Equivalent Circuit



Voltage noise of amplifier

$$\overline{i_{sh}^2} = 2qI_pFB \quad (A^2)$$

$$\overline{i_{th}^2} = \frac{4KTB_{Rx}}{R_T}$$

Note,  $R_L \gg R_F$ , therefore

$$\overline{i_{th}^2} = \frac{4KTB_{Rx}}{R_F}$$

and

$$V_o = \frac{-R_F G_{PD} I_o}{\left(1 + \frac{j2\pi f C_T R_F}{A_v}\right)}$$

# OWC – Rx – TIFA – Equivalent Circuit

For PIN PD,  $G_{PD} = 1$

Total noise power  
[bandwidth is considered  
in all noise terms]

$$\overline{i_{nT}^2} = \overbrace{\overline{i_{sh}^2} + \overline{i_{dc}^2} + \overline{i_{th}^2}}^{\text{PD noise current } \overline{i_{n-PD}^2}} + \overbrace{\overline{i_{amp}^2} + \overline{v_{amp}^2}/R_F}^{\text{Amp. noise current } \overline{i_{n-amp}^2}} \quad \left. \vphantom{\overline{i_{nT}^2}} \right\} \text{Frequency dependent noise}$$

Total input noise current  $i_{n-in} = \sqrt{\overline{i_{nT}^2}}$  → Total output noise voltage  $v_{n-out} = i_{n-in} R_F$

RMS noise voltage  $v_{n-out-RMS} = v_{n-out} \sqrt{B_n}$

Noise bandwidth

# OWC – Rx – TIFA – Noise

Noise is determined by

Input capacitance  $C_{in} = C_{PD} + C_{amp}$

Feedback capacitance  $C_F$

Shunt resistance  $R_L$

Feedback resistance  $R_F$

Shape the noise gain  $G_n$

$$G_n = \frac{v_{n-out}}{v_{n-amp}} = \frac{R_F(C_{in} + C_F) + 1}{R_F C_F + 1}$$

Cause a peak in  $G_n$

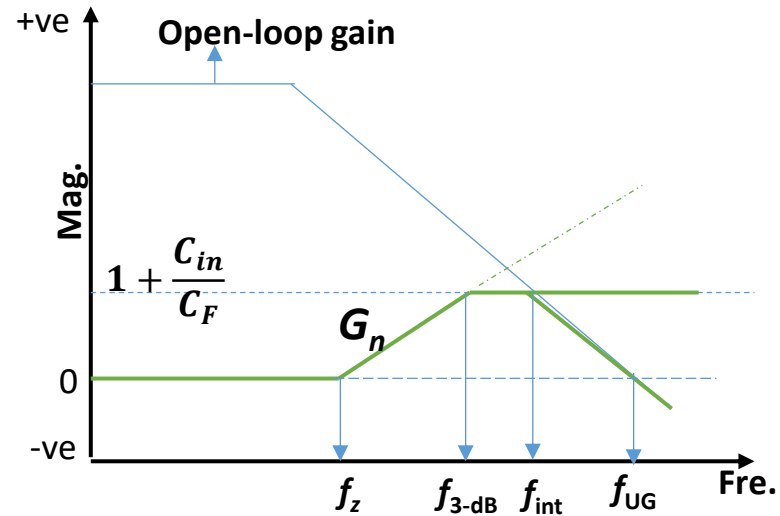
Zero frequency

$$f_z = \frac{1}{2\pi R_F (C_{in} + C_F)}$$

Pole (3-dB) frequency

$$f_{3-dB} = \frac{1}{2\pi R_F C_F}$$

# OWC – Rx – TIFA – Noise



$$f_{\text{int}} = f_{\text{UG}} \frac{C_F}{C_F + C_{in}}$$

↓  
Unity gain frequency

$$C_{F\text{-min}} \cong \sqrt{\frac{C_{in}}{2\pi R_F f_{\text{UG}}}}$$

Is very small

Stable amplifier

# OWC – Rx – TIFA – Noise

Total current noise PSD

$$i_{nT}^2 = N_{iT} B_{Rx} + \frac{(2\pi v_{amp} C_T)^2}{3} B_{Rx}^3$$

$$C_{PD} \gg C_{T,opt}$$



Voltage noise dominates

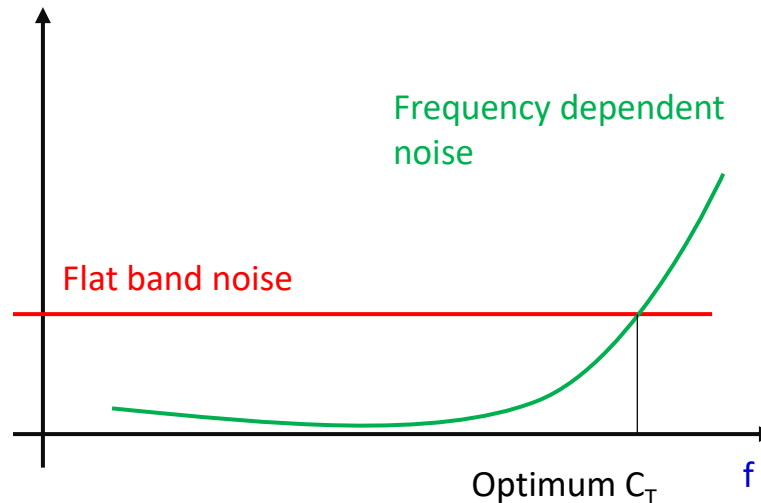
$$C_{PD} \ll C_{T,opt}$$



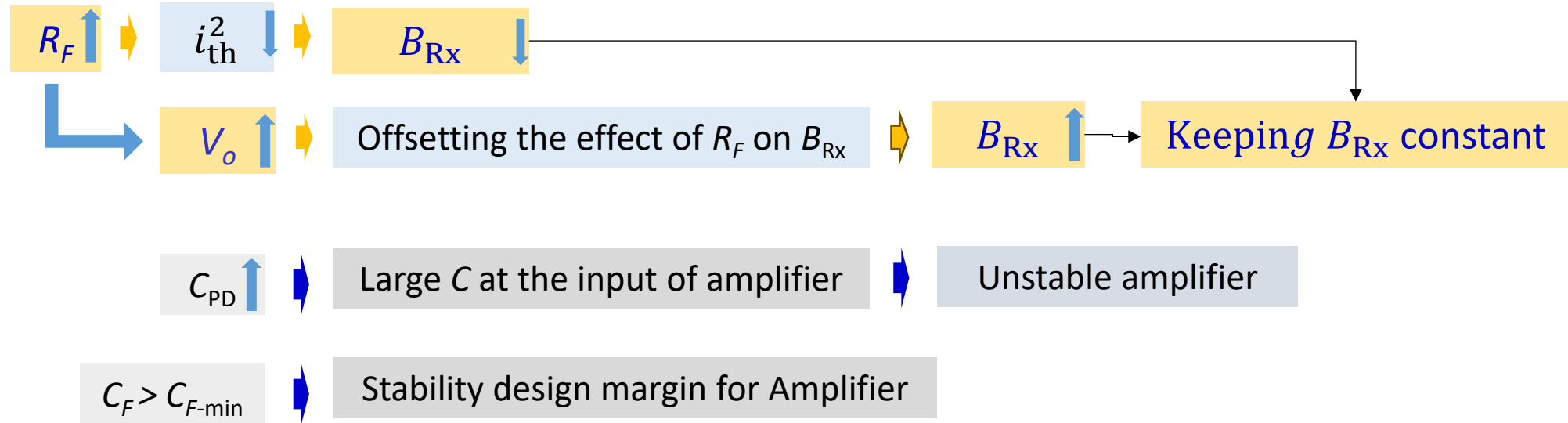
$C_{amp}$  becomes critical – Keep it small

$$C_{T,opt} = \frac{\sqrt{3N_{iT}}}{2\pi v_{amp} B_{Rx}}$$

Optimized to meet the flat band noise



# OWC – Rx – TIFA – Equivalent Circuit



## Trade-Offs in TIA Design



$P_{o-max}$  for which it will deliver an acceptable BER. Overload can also be defined by an acceptable limit on jitter.

# OWC – Rx – Performance Metrics - SNR

There is no universal definition of SNR, therefore, have adopt a convention for both electrical and optical SNRs:

Note:

Noise power spectral density (PSD)

$$\text{Noise power } N = N_o \times B$$

Signal power  $P_{ave} = \frac{1}{T} \int_0^T v^2(t) dt$  Or  $P = \int_{0a}^b PSD_s df$

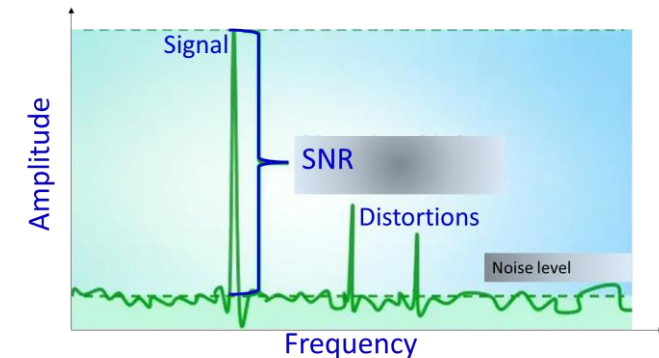
$$SNR_{ele} = \frac{\text{Avg. signal power}}{\text{Electrical noise power}} = \frac{P_{avg}}{N_{ele}}$$

Noise variance

$$\text{Note: } N_{ele} = (\sigma_{ele})^2$$

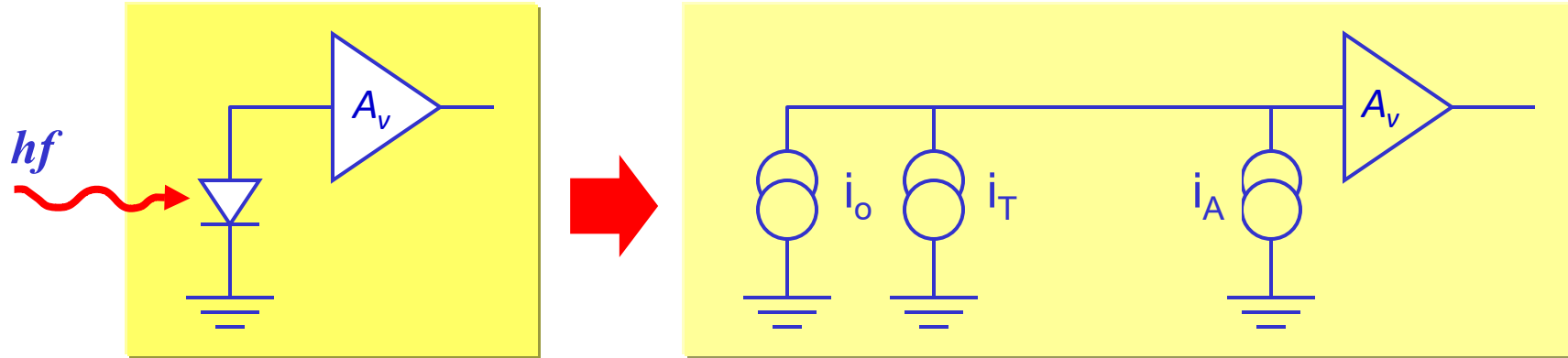
$$SNR_{opt} = \frac{\text{Avg. signal power}}{\text{Optical noise power}} = \frac{P_o}{N_{opt}}$$

$$\text{Note: } N_{opt} = \sigma \propto P_o$$



One fundamental design limit would be for the noise at the “0” level to be negligible (i.e.,  $\sigma_0 = 0$  compared to the noise at the “1” level. This would be for an **ideal noiseless detector** and is called the **“shot noise limit”**. This is an ultimate goal or fundamental limit that is used as a base to compare real systems.

# OWC – Rx – PM - SNR



$$\text{SNR} = \frac{\overline{i_p^2}}{\overline{i_{nT}^2}} \left\{ \begin{array}{l} \bullet \text{ PIN} \\ \bullet \text{ APD} \end{array} \right.$$

$$\text{SNR}_{\text{PIN}} = \frac{I_o^2}{2qB(I_p + I_{dc}) + \frac{4KTB}{R_L} + \overline{i_A^2}}$$

$$\text{SNR}_{\text{APD}} = \frac{G_{\text{APD}}^2 I_o^2}{2qB[(I_p + I_{dc})G_{\text{APD}}^2 F] + \frac{4KTB}{R_L} F + \overline{i_A^2}}$$

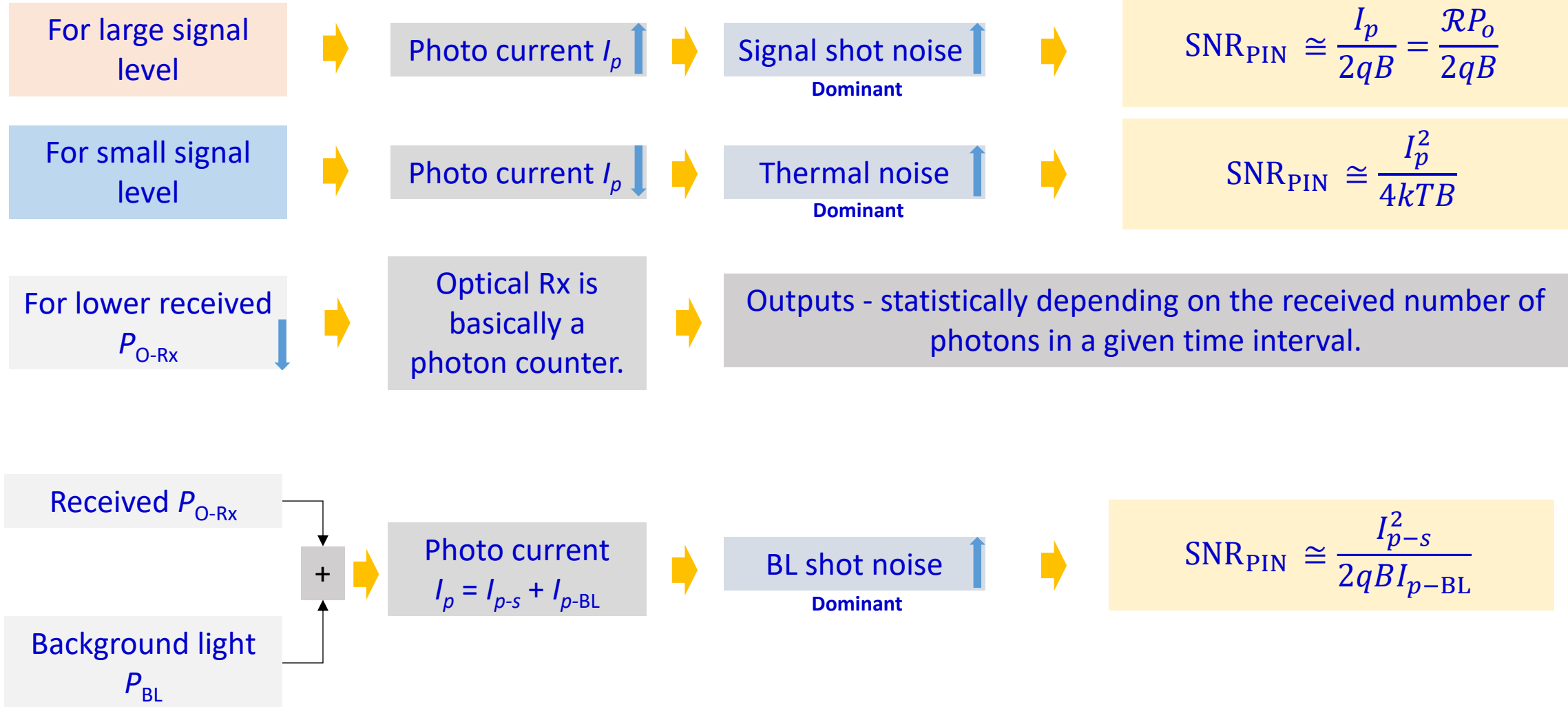
Note: SNR cannot be improved by amplification, since noise is also amplified!

## SNR - Quantum Limit – Shot noise

$$\text{SNR}_{\text{QL}} = \frac{I_p(I_p)}{2qI_pB} = \frac{RP_o/hf}{2B} = \frac{re}{B} = \frac{n_{\text{electron/s}}}{\text{bit/s}} = \frac{n_{\text{electron}}}{\text{bit}} = N$$

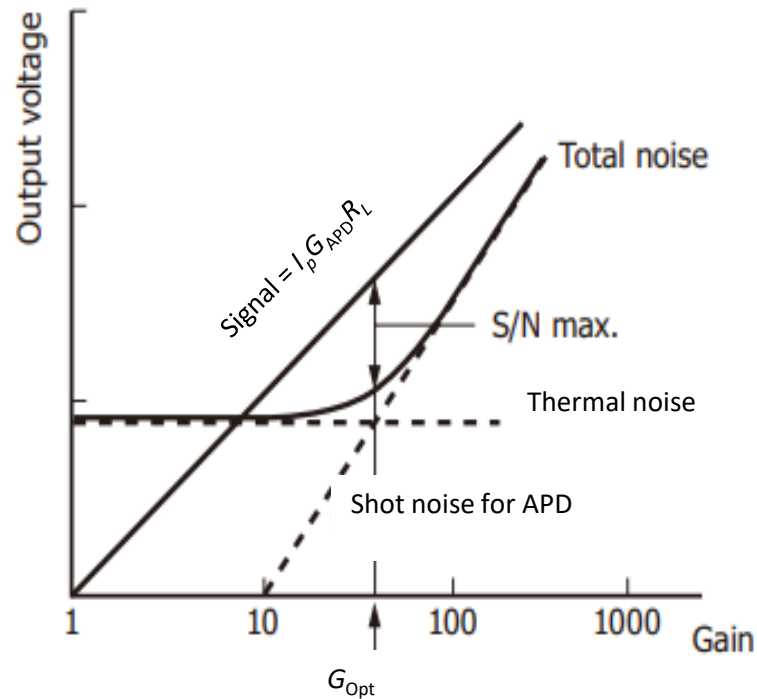
# OWC – Rx – PM - SNR

Lead to 



BL is modelled as a source with a constant photon arrival rate.

For APD – The shot noise could be at the same level as the thermal noise due to the internal gain → improved SNR

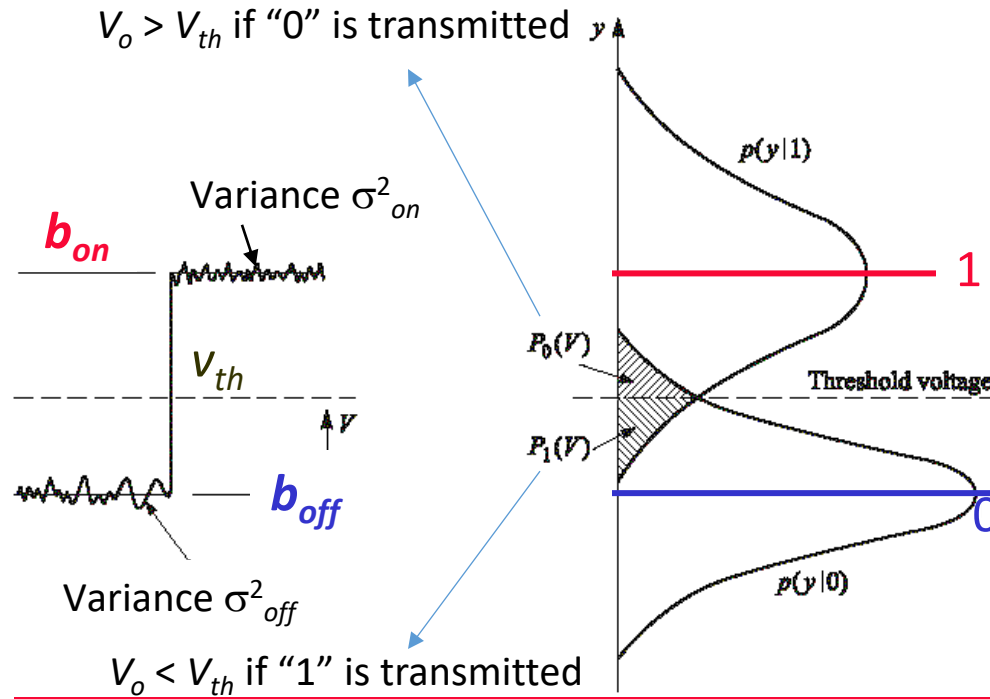


Optimum gain  $G_{\text{opt}} = \left[ \frac{4kT}{q(I_p + I_{\text{dc}})R_L} \right]^{\frac{1}{2+x}}$

# OWC – Rx – PM - BER

## Using a simple threshold detection at the Rx

**Probability of Error (or bit error rate (BER))** = Probability that the output signal level (voltage) is less than the threshold when a 1 is sent + probability that the output voltage is more than the threshold when a 0 has been sent



Assuming that the probabilities of 0 and 1 pulses are equally likely, we have:

$$BER = P_e = \frac{1}{2} \left[ 1 - \operatorname{erf} \left( \frac{Q}{\sqrt{2}} \right) \right]$$

$$Q = \left[ \frac{v_{th} - b_{off}}{\sigma_{off}} \right] = \left[ \frac{b_{on} - v_{th}}{\sigma_{on}} \right]$$

$$\begin{aligned} P_e &= q_1 P_1(v_{th}) + q_0 P_0(v_{th}) \\ &= q_1 \int_{-\infty}^{v_{th}} p(y|1) dy + q_0 \int_{v_{th}}^{\infty} p(y|0) dy \end{aligned}$$

where  $q_1$  and  $q_0$  are probabilities that the transmitter sends 0 and 1 respectively.  
Note,  $q_0 = 1 - q_1$ .

For

- $\sigma_{off} = \sigma_{on} = \sigma$  i.e., the RMS noise
- $b_{on} = V$ , and  $b_{off} = 0$
- Thus,  $v_{th} = V/2$  and  $Q = V/2\sigma$

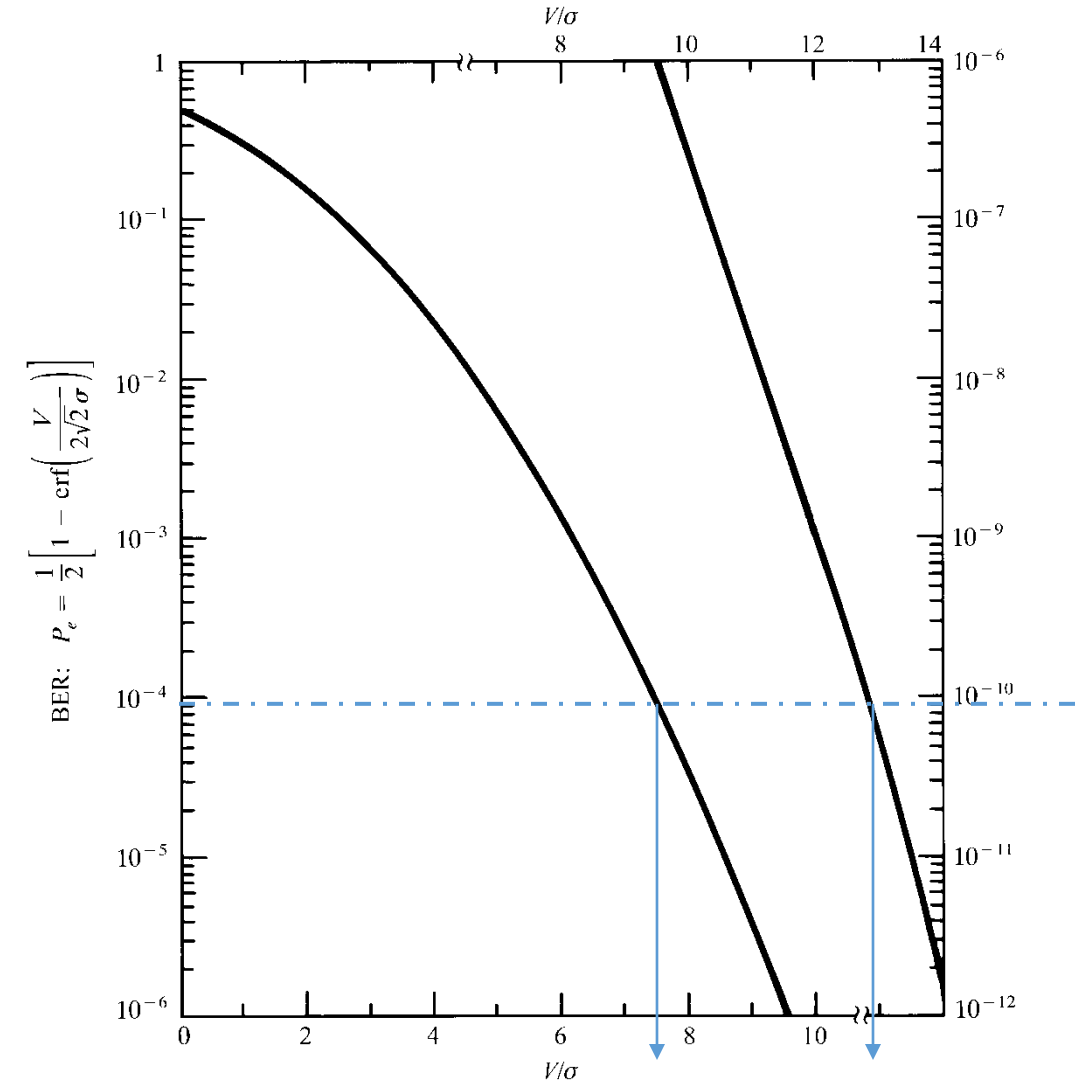
Therefore: 
$$BER = P_e = \frac{1}{2} \left[ 1 - \operatorname{erf} \left( \frac{V}{2\sqrt{2}\sigma} \right) \right]$$

In terms of power signal-to-noise ratio (SNR), we have:

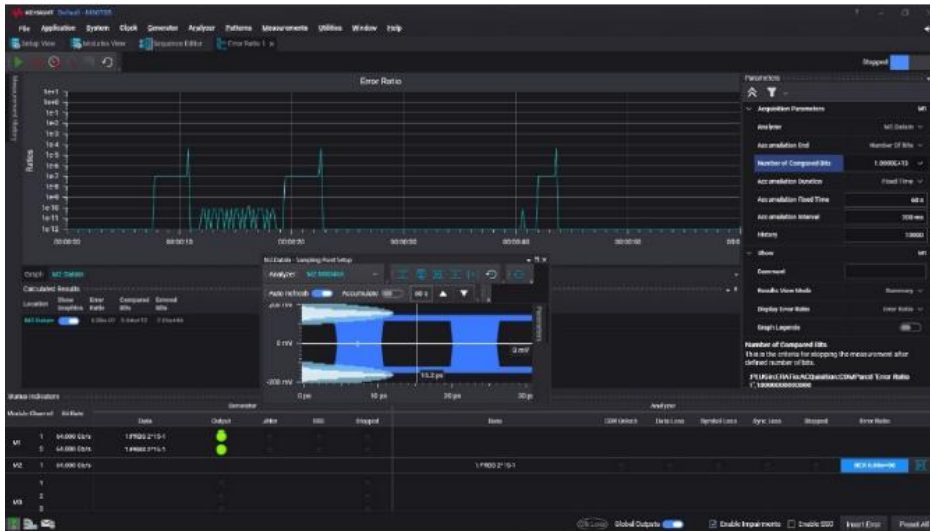
$$BER = P_e = \frac{1}{2} \left[ 1 - \operatorname{erf} (0.345\sqrt{SNR}) \right]$$

BER can also be defined in terms of Energy per bit  $E_b$  and noise power spectral density  $N_o$  :

$$BER = \frac{1}{2} \left[ 1 - \operatorname{erf} \left( \sqrt{\frac{E_b}{N_o}} \right) \right]$$



# OWC – Rx – SNR – PM – BER Measurement



With Real-Time Oscilloscope Integrated in M8070B Software  
Keysight Technologies

For BER measurement:

Use a PRBS test pattern generator

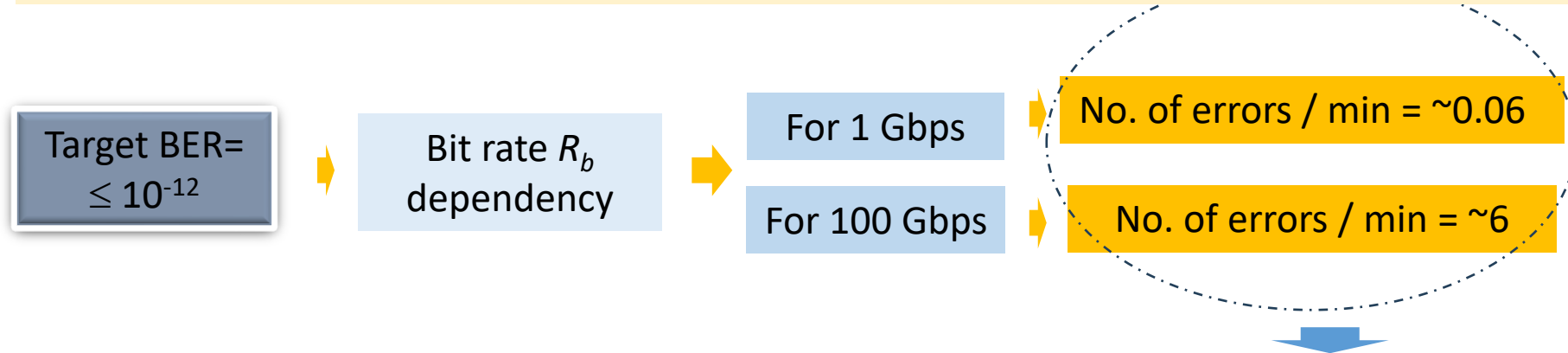
Use a real-time digital oscilloscope to capture and stores at least two error-free copies of an identical repeating patterns

Compares the subsequently measured bit patterns with those saved patterns

Determines the BER

# OWC – Rx – SNR – PM - BER

Optical network



- There is a big difference.
- So, how to ensure that 1 Gbps measurement is as reliable as 100 Gbps.

$$CL = 1 - e^{-N_{\text{bits}} * BER}$$

Need to consider the Confidence Level (CL) – A statistical value

Next, determine the measurement time  
 $T_m = N_{\text{bits}} / R_b$

Then, determine the number of bits required for a given BER – Use the Poisson distribution

$$N_{\text{bits}} = -\frac{\ln(1 - CL)}{BER}$$

# OWC – Rx – SNR – PM - BER

Confidence level (CL) %	Required bits for BER, e.g., $\leq 10^{-12}$
90	$2.3 \times 10^{12}$
95	$3 \times 10^{12}$
99	$4.6 \times 10^{12}$
99.9	$6.9 \times 10^{12}$

$$N_{\text{bits}} = -\frac{\ln(1 - \text{CL})}{\text{BER}}$$



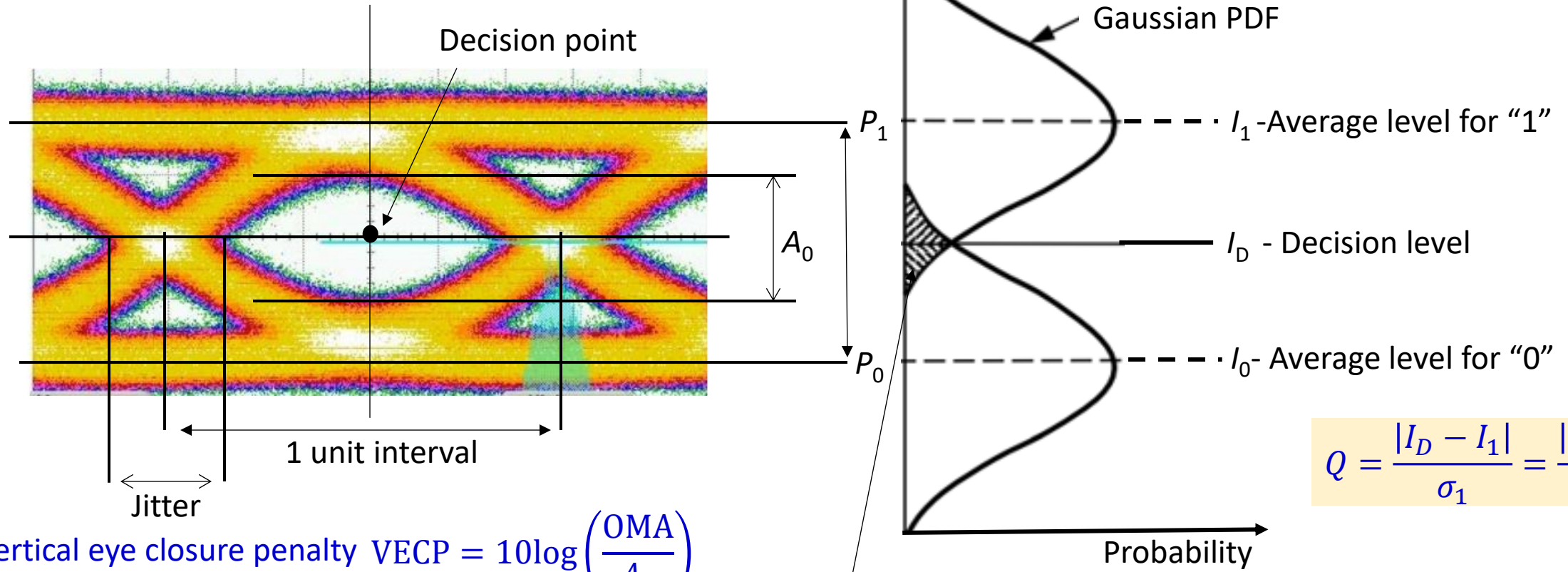
Data rate	Measurement time $T_m$
1 Gbps	38.5 m
100 Gbps	23 s

$$T_m = N_{\text{bits}} / R_b$$

# OWC – Rx – SNR – PM – Eye Diagram

The eye diagram. It:

- provides a quick and intuitive method to assess the quality of a digital communications
- is an oscilloscope display of the digital signal triggered at the clock rate or a divided clock rate
- contains every possible bit sequence.



Vertical eye closure penalty  $VECP = 10\log\left(\frac{OMA}{A_0}\right)$

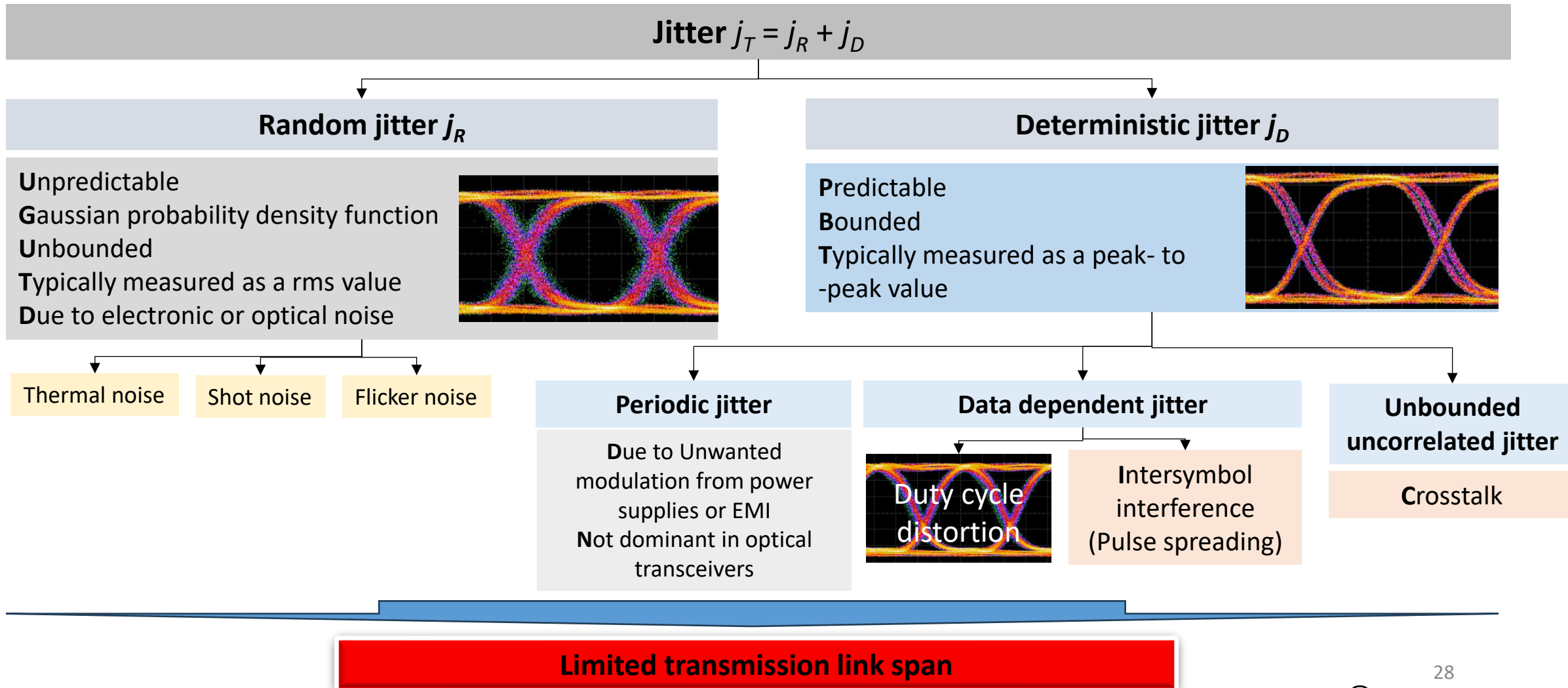
$OMA = P_1 - P_0$

$$Q = \frac{|I_D - I_1|}{\sigma_1} = \frac{|I_D - I_0|}{\sigma_0}$$

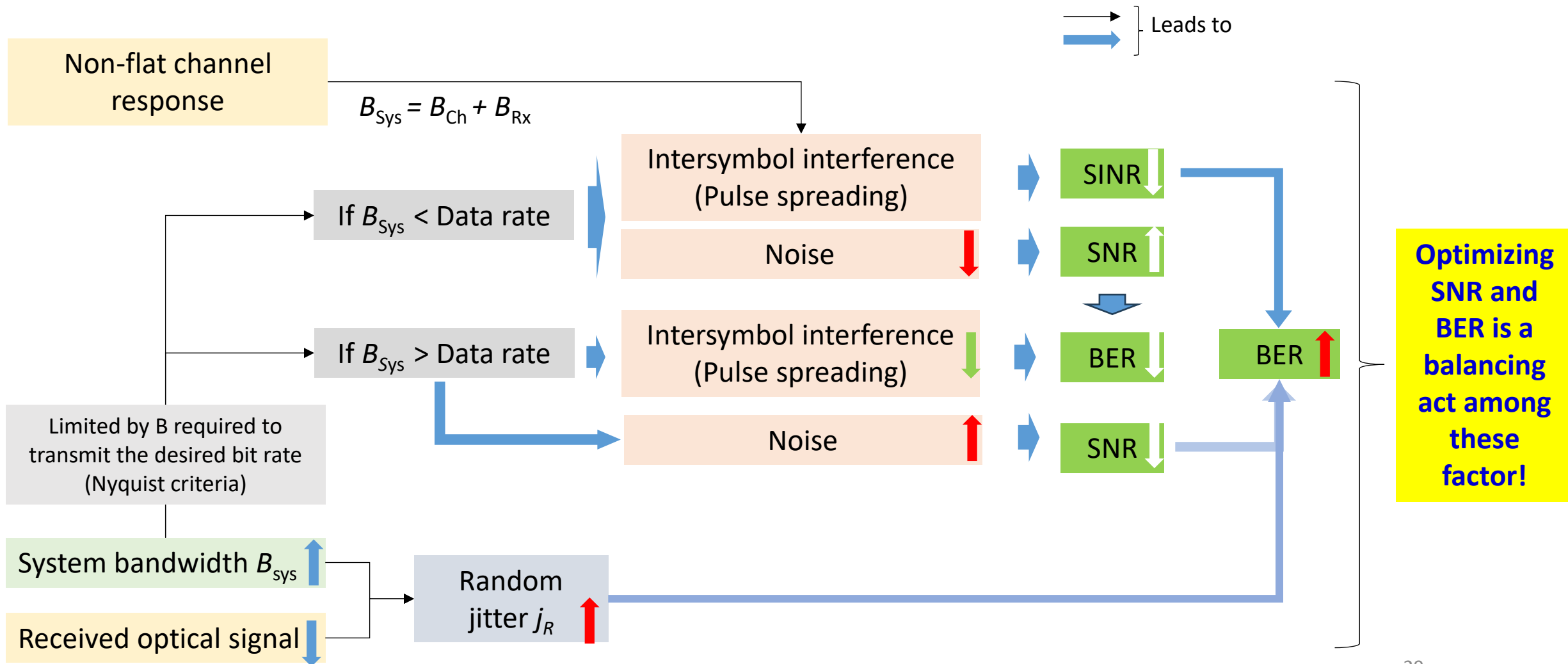
Probability of incorrect detection

# OWC – Rx – SNR – PM – Eye Diagram - Jitter

- Jitter is the variation in the data transition instant (1 to 0 or 0 to 1) with respect to its expected position.
- The Rx specifications will specify certain tolerance of the amount of jitter across a certain jitter modulation range.



## Performance indicators

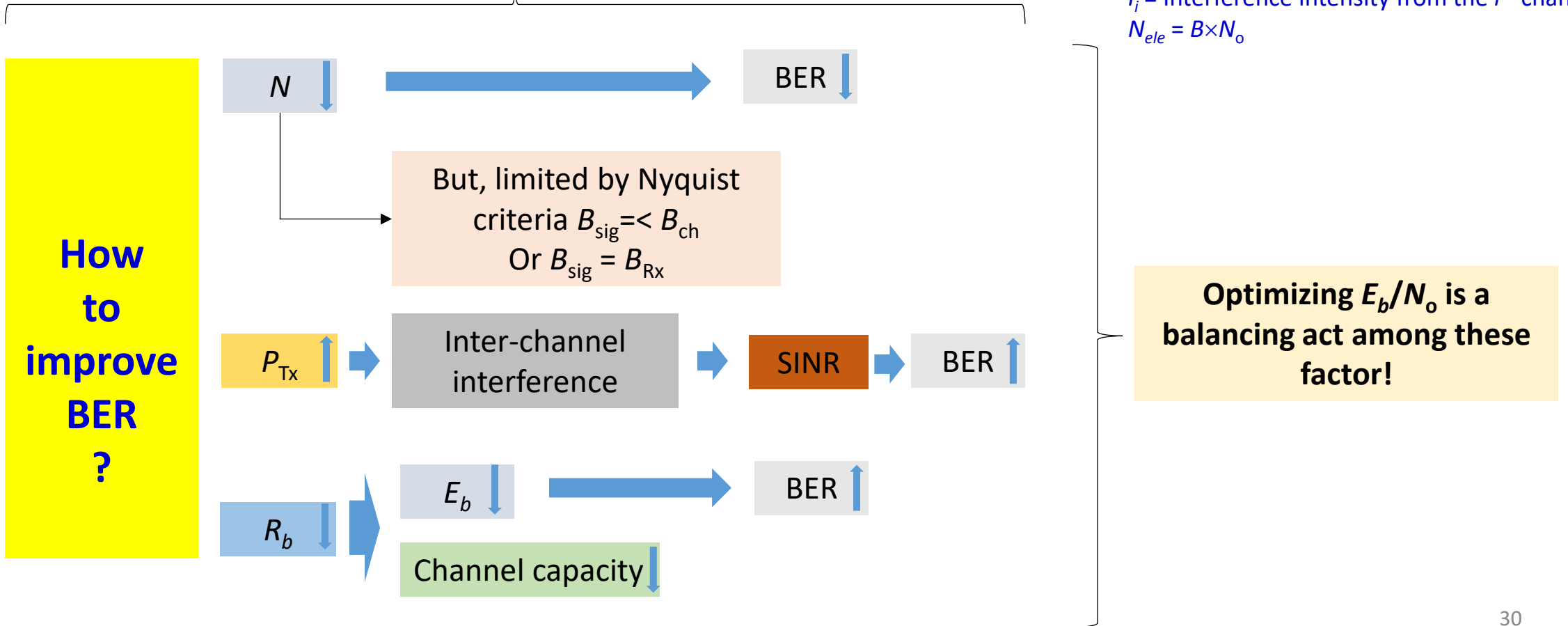


$$\text{BER} = \frac{1}{2} \left[ 1 - \text{erf} \left( \sqrt{\frac{E_b}{N_o}} \right) \right]$$

$$\text{SINR}_{\text{opt}} = \frac{P_o}{I_i + N_{\text{opt}}}$$

$$\text{SINR}_{\text{ele}} = \frac{(\mathcal{R}P_o)^2}{(I_i)^2 + N_{\text{ele}}}$$

$I_i$  = Interference intensity from the  $i^{\text{th}}$  channel  
 $N_{\text{ele}} = B \times N_o$



**Thank you!**